# **CNA1302K** (ON1004)

## Photo Interrupter

For contactless SW and object detection

#### Overview

CNA1302K is an ultraminiature, highly reliable transmissive photosensor in which a high efficiency GaAs infrared light emitting diode chip and a high sensitivity Si phototransistor chip are integrated in a double molded resin package.

#### Features

- Ultraminiature: 4.2 mm × 5.0 mm (height: 5.2 mm)
- Fast response:  $t_r$ ,  $t_f = 35 \mu s$  (typ.)
- Highly precise position detection: 0.15 mm
- Gap width: 2.0 mm

### ■ Absolute Maximum Ratings $T_a = 25$ °C

| F                            | Symbol                                | Rating           | Unit |    |
|------------------------------|---------------------------------------|------------------|------|----|
| Input (Light emitting diode) | Power dissipation *1                  | $P_{\mathrm{D}}$ | 75   | mW |
|                              | Forward current                       | $I_{\mathrm{F}}$ | 50   | mA |
|                              | Reverse voltage                       | $V_{R}$          | 6    | V  |
| Output<br>(Photo transistor) | Collector-emitter voltage (Base open) | V <sub>CEO</sub> | 35   | ON |
|                              | Emitter-collector voltage (Base open) | V <sub>ECO</sub> | 6    | v  |
|                              | Collector current                     | $I_{C}$          | 20   | mA |
|                              | Collector power dissipation *2        | $P_{\rm C}$      | 75   | mW |
| Operating ambient temp       | Topr                                  | -25 to +85       | °C   |    |
| Storage temperature          | $T_{\rm stg}$                         | -40 to +100      | °C   |    |

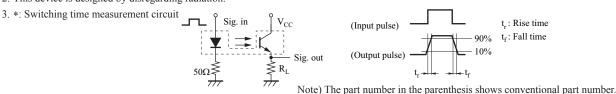
Note) \*1: Input power derating ratio is 1.0 mW/°C at  $T_a \ge 25$ °C

#### ■ Electrical-Optical Characteristics $T_a = 25$ °C±3°C

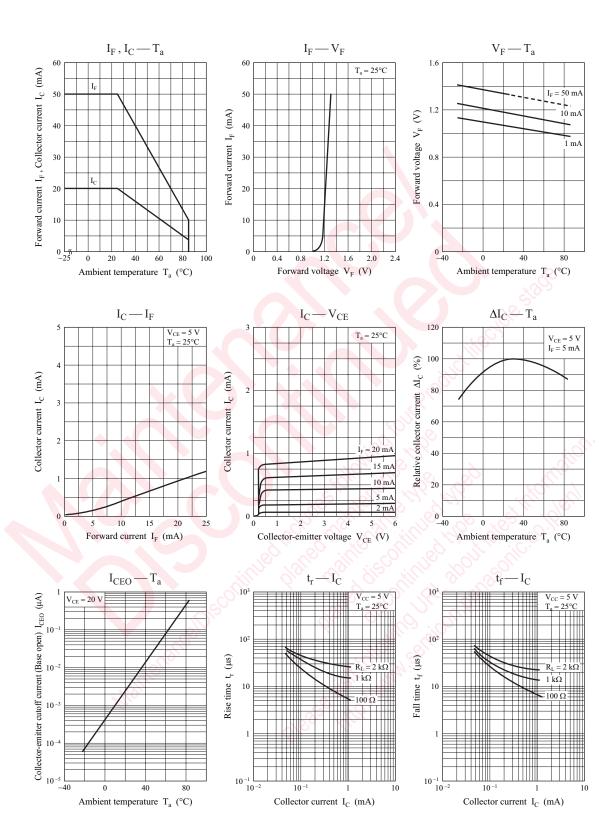
| Parameter                |  | Symbol               | Conditions                                      | Min | Тур | Max | Unit |
|--------------------------|--|----------------------|---|-----|-----|-----|------|
| Input characteristics    | Reverse current                              | $I_R$                | $V_R = 3 V$                                     |     |     | 10  | μΑ   |
|                          | Forward voltage                              | V <sub>F</sub>       | $I_F = 20 \text{ mA}$                           |     | 1.2 | 1.4 | V    |
| Output characteristics   | Collector-emitter cutoff current (Base open) | I <sub>CEO</sub>     | $V_{CE} = 20 \text{ V}$                         |     |     | 100 | nA   |
| Transfer characteristics | Collector current                            | $I_{\rm C}$          | $V_{CE} = 5 \text{ V}, I_F = 5 \text{ mA}$      | 40  |     | 400 | μΑ   |
|                          | Collector-emitter saturation voltage         | V <sub>CE(sat)</sub> | $I_F = 10 \text{ mA}, I_C = 40 \mu\text{A}$     |     |     | 0.4 | V    |
|                          | Rise time *                                  | t <sub>r</sub>       | $V_{CC} = 5 \text{ V}, I_{C} = 0.1 \text{ mA},$ |     | 35  |     | μs   |
|                          | Fall time *                                  | $t_{\mathrm{f}}$     | $R_{\rm L} = 1000\Omega$                        |     | 35  |     | μs   |

Note) 1. Input and output are practiced by electricity.

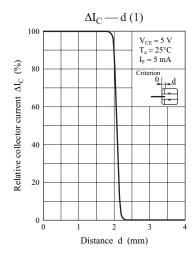
2. This device is designed by disregarding radiation.

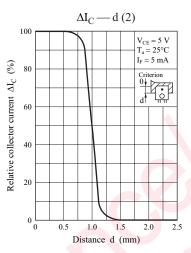


<sup>\*2:</sup> Output power derating ratio is 1.0 mW/°C at  $T_a \ge 25$ °C



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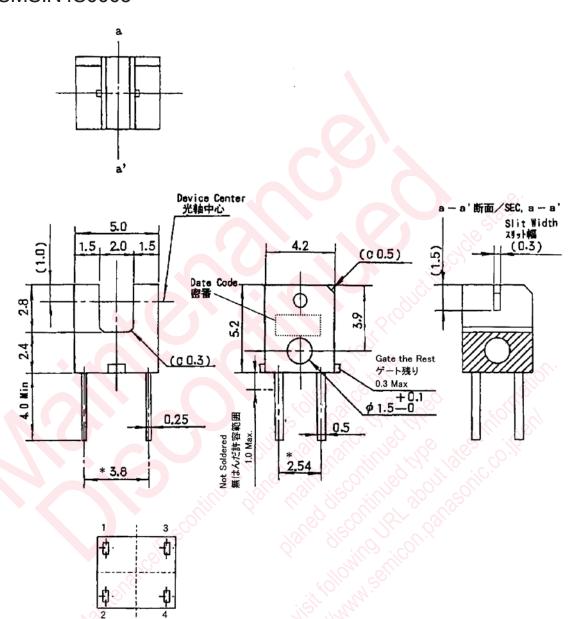




## **Panasonic**

#### ■ Package (Unit: mm)

## LSMSIN4S0005



- (注 1)(Note1) \* リード根元寸法とします/ \* Indicates root dimensions of lead.
- (注 2)(Note2)指示無き寸法公差は±0.2/Not appointment tolerance :±0.2
- (注 3)(Note3)パリ寸法は 0.15 Max./Barri measure : 0.15 Max.
- (注 4) 上記寸法は、バリ・ゲート残り等を含んでおりません

(Note4)An aforementioned dimension doesn't include projects and gate the rest remainder.

(注 5) 密番は、目視又は顕微鏡に於いて解読できる事

(Note5)What a date code sees an attention and can decode in a microscope.

- Pin name
  - 1: Anode
  - 2: Cathode
  - 3: Collector
  - 4: Emitter

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